Silicon Power Transistors

The NJW21193G and NJW21194G utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

Features

- Total Harmonic Distortion Characterized
- High DC Current Gain
- Excellent Gain Linearity
- High SOA
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|-----------------------------------|-----------------|-----------|
| Collector-Emitter Voltage | V _{CEO} | 250 | Vdc |
| Collector-Base Voltage | V _{CBO} | 400 | Vdc |
| Emitter-Base Voltage | V _{EBO} | 5.0 | Vdc |
| Collector-Emitter Voltage - 1.5 V | V _{CEX} | 400 | Vdc |
| Collector Current - Continuous | I _C | 16 | Adc |
| Collector Current - Peak (Note 1) | I _{CM} | 30 | Adc |
| Base Current - Continuous | I _B | 5.0 | Adc |
| Total Power Dissipation @ T _C = 25°C Derate Above 25°C | P _D | 200 1.6 | W W/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | – 65 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Pulse Test: Pulse Width = 5 μs, Duty Cycle ≤ 10%.

THERMAL CHARACTERISTICS

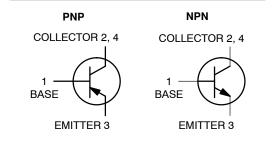
| Characteristic | Symbol | Max | Unit |
|--|----------------|-------|------|
| Thermal Resistance, Junction-to-Case | $R_{	heta JC}$ | 0.625 | °C/W |
| Thermal Resistance, Junction-to-Ambient | $R_{	heta JA}$ | 40 | °C/W |

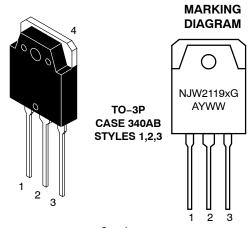


ON Semiconductor®

http://onsemi.com

16 AMPERES COMPLEMENTARY SILICON **POWER TRANSISTORS 250 VOLTS, 200 WATTS**





= 3 or 4

G = Pb-Free Package = Assembly Location

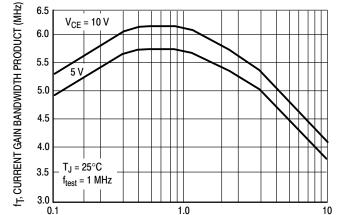
= Year WW = Work Week

ORDERING INFORMATION

| Device | Package | Shipping |
|-----------|--------------------|---------------|
| NJW21193G | TO-3P (Pb-Free) | 30 Units/Rail |
| NJW21194G | TO-3P (Pb-Free) | 30 Units/Rail |

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|---|-----------------------|-------------|--------|----------|------|
| OFF CHARACTERISTICS | | | • | • | |
| Collector–Emitter Sustaining Voltage ($I_C = 100 \text{ mAdc}, I_B = 0$) | V _{CEO(sus)} | 250 | _ | - | Vdc |
| Collector Cutoff Current (V _{CE} = 200 Vdc, I _B = 0) | I _{CEO} | - | - | 100 | μAdc |
| Emitter Cutoff Current (V _{CE} = 5 Vdc, I _C = 0) | I _{EBO} | - | - | 100 | μAdc |
| Collector Cutoff Current (V _{CE} = 250 Vdc, V _{BE(off)} = 1.5 Vdc) | I _{CEX} | - | - | 100 | μAdc |
| ECOND BREAKDOWN | | | | | |
| Second Breakdown Collector Current with Base Forward Biased (V _{CE} = 50 Vdc, t = 1 s (non-repetitive) (V _{CE} = 80 Vdc, t = 1 s (non-repetitive) | I _{S/b} | 4.0 2.25 | _ _ | _ _ | Adc |
| ON CHARACTERISTICS | , | | | • | |
| DC Current Gain $(I_C = 8 \text{ Adc}, V_{CE} = 5 \text{ Vdc})$ $(I_C = 16 \text{ Adc}, I_B = 5 \text{ Adc})$ | h _{FE} | 20 8 | _ _ | 80 - | |
| Base-Emitter On Voltage (I _C = 8 Adc, V _{CE} = 5 Vdc) | V _{BE(on)} | - | _ | 2.2 | Vdc |
| Collector–Emitter Saturation Voltage ($I_C = 8$ Adc, $I_B = 0.8$ Adc) ($I_C = 16$ Adc, $I_B = 3.2$ Adc) | V _{CE(sat)} | - - | - - | 1.4 4 | Vdc |
| DYNAMIC CHARACTERISTICS | | | | | |
| Total Harmonic Distortion at the Output V_{RMS} = 28.3 V, f = 1 kHz, P_{LOAD} = 100 W_{RMS} h_{FE} unmatched | T _{HD} | _ | 0.8 | _ | % |
| (Matched pair h_{FE} = 50 @ 5 A/5 V) h_{FE} matched | | - | 0.08 | _ | |
| Current Gain Bandwidth Product (I _C = 1 Adc, V _{CE} = 10 Vdc, f _{test} = 1 MHz) | f _T | 4 | - | - | MHz |
| Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz) | C _{ob} | - | - | 500 | pF |



PNP NJW21193G

Figure 1. Typical Current Gain Bandwidth Product

I_C COLLECTOR CURRENT (AMPS)

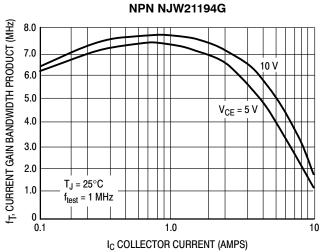


Figure 2. Typical Current Gain Bandwidth Product

TYPICAL CHARACTERISTICS

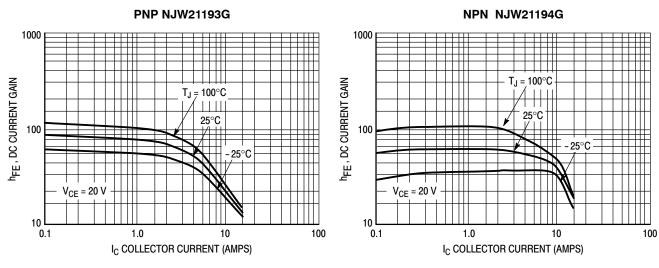


Figure 3. DC Current Gain, V_{CE} = 20 V

Figure 4. DC Current Gain, V_{CE} = 20 V

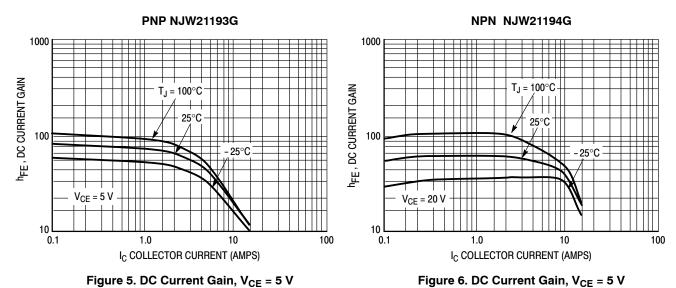


Figure 5. DC Current Gain, V_{CE} = 5 V

PNP NJW21193G NPN NJW21194G 30 35 I_B = 2 A 1.5 A $I_B = 2 A$ 30 25 I_C, COLLECTOR CURRENT (A) _{(C}, COLLECTOR CURRENT (A) 1.5 A 25 20 1 A 1 A 20 15 0.5 A 15 0.5 A 10 10 5.0 $T_J=25^{\circ}C$ $T_J = 25^{\circ}C$ 0 0 25 15 0 5.0 25 V_{CE}, COLLECTOR-EMITTER VOLTAGE (VOLTS) V_{CE}, COLLECTOR-EMITTER VOLTAGE (VOLTS)

Figure 7. Typical Output Characteristics

Figure 8. Typical Output Characteristics

TYPICAL CHARACTERISTICS

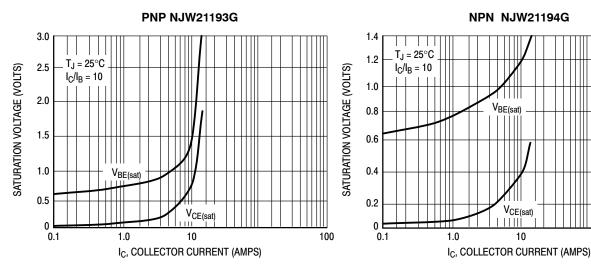


Figure 9. Typical Saturation Voltages

Figure 10. Typical Saturation Voltages

100

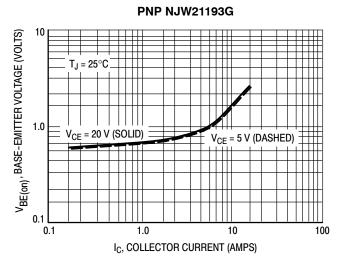


Figure 11. Typical Base-Emitter Voltage

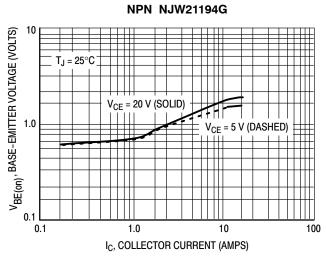


Figure 12. Typical Base-Emitter Voltage

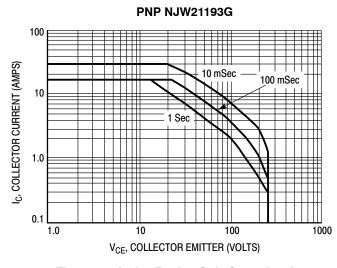


Figure 13. Active Region Safe Operating Area

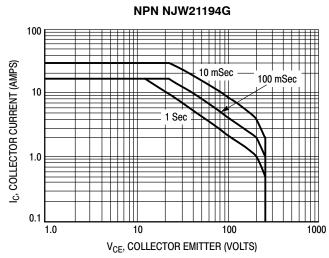


Figure 14. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on $T_{J(pk)} = 150^{\circ}C$; T_{C} is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

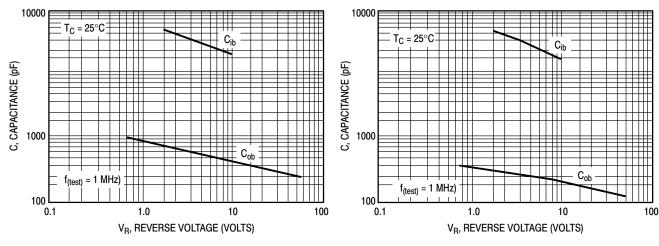


Figure 15. NJW21193G Typical Capacitance

Figure 16. NJW21194G Typical Capacitance

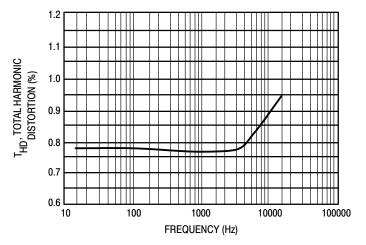


Figure 17. Typical Total Harmonic Distortion

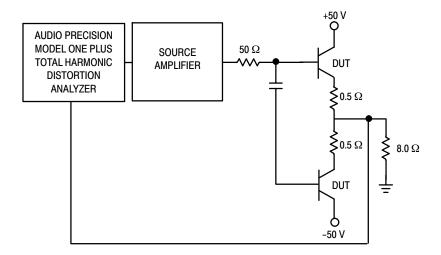
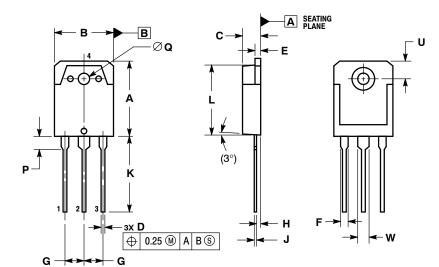


Figure 18. Total Harmonic Distortion Test Circuit

PACKAGE DIMENSIONS

TO-3P-3LD CASE 340AB-01 **ISSUE A**



- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM THE TERMINAL TIP.
- DIMENSION A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIMETERS | | | |
|-----|-------------|-------|-------|--|
| DIM | MIN | NOM | MAX | |
| Α | 19.70 | 19.90 | 20.10 | |
| В | 15.40 | 15.60 | 15.80 | |
| C | 4.60 | 4.80 | 5.00 | |
| D | 0.80 | 1.00 | 1.20 | |
| E | 1.45 | 1.50 | 1.65 | |
| F | 1.80 | 2.00 | 2.20 | |
| G | 5.45 BSC | | | |
| Н | 1.20 | 1.40 | 1.60 | |
| J | 0.55 | 0.60 | 0.75 | |
| K | 19.80 | 20.00 | 20.20 | |
| L | 18.50 | 18.70 | 18.90 | |
| P | 3.30 | 3.50 | 3.70 | |
| Q | 3.10 | 3.20 | 3.50 | |
| U | 5.00 REF | | | |
| W | 2.80 | 3.00 | 3.20 | |

ANODE

CATHODE

STYLE 1: BASE PIN 1.

- 2. COLLECTOR
- 3. **EMITTER**
- COLLECTOR

STYLE 2: STYLE 3: PIN 1. ANODE 2. CATHODE

- PIN 1. GATE 2. DRAIN
 - DRAIN
 - 3. SOURCE DRAIN

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, ON semiconductor and war registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking, pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implications the polar or other applications intended to surgical implications which the failure of the SCILLC expects existing where surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada **Fax**: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

AMEYA360 Components Supply Platform

Authorized Distribution Brand:

























Website:

Welcome to visit www.ameya360.com

Contact Us:

> Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com